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POLYMER MATERIALS

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Direct Quantitative Characterization of Polymer Brushes Obtained ² by Surface-Initiated ATRP on Silicon

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14 the covalent grafting of atom transfer radical polymerization 15 (ATRP) initiators on a hydrogenated silicon surface and the 16 subsequent polymerization of styrene. Three prefunctionalized 17 surfaces designated Si-Br1, Si-Br2, and Si-Br3 are obtained by 18 different procedures. The initiator grafting densities obtained by



19 quantitative IR are 1.7 ± 0.3 nm⁻² for Si-Br1, 1.5 ± 0.3 nm⁻² for Si-Br2, and 0.9 ± 0.2 nm⁻² for Si-Br3. After the polymerization of 20 styrene under the same experimental conditions (grafting from without sacrificial initiators) and a careful Soxhlet rinse to remove 21 physisorbed polymers formed in solution, almost no polymerization is observed using Si-Br1 with a value of the density in 22 polymerized styrene units of $12 \pm 2 \text{ nm}^{-2}$, which is probably due to the chelating effect of the amino linkers used for grafting the 23 initiators in Si-Br1. In contrast, the densities in styrene units are $54 \pm 11 \text{ nm}^{-2}$ using Si-Br2 and $141 \pm 28 \text{ nm}^{-2}$ using Si-Br3. The 24 degree of polymerization (DP) has been evaluated by measuring the polymer thickness (by ellipsometry and atomic force 25 microscopy, AFM) and using a scaling law relating the latter to DP for dry polymer brushes. High DP values of 200 and 1000 are 26 found in the case of Si-Br2 and Si-Br3, respectively. The fraction of active polymerization initiators is found to be 15-18%, 27 independent of the initiator surface density. In contrast, polymerization kinetics appear affected by steric hindrance and 28 conformational disorder among grafted initiators. This approach for determining surface densities of grafted initiators and grafted 29 polymer chains and DPs is fully generalizable to any other polymer system.

30 KEYWORDS: SI-ATRP, polymerization, silicon, IR-ATR, surface functionalization

1. INTRODUCTION

31 The preparation of functionalized surfaces from already 32 existing materials is a booming activity in materials sciences 33 as attested by the numerous recent reviews in the field.¹⁻⁵ 34 Thus, using a very modest amount of reactant, it is possible to 35 give properties and a very high added value to a basic and 36 relatively inexpensive material. Often, functionalization with a 37 monolayer is not sufficient to give the material the desired 38 property, hence the need to use a layer of polymers to obtain 39 sufficient thickness. The fields of application concerned are 40 immense and diverse and depend on the type of sought 41 properties and therefore on the type of functional entities $_{42}$ attached at the surface of the material.⁶⁻⁸ They encompass 43 medical and public health field, $^{9-12}$ antifouling coatings in the 44 marine environment,¹³ self-cleaning day-life textiles,¹⁴ treat-45 ment of drinking water,¹⁵ recovery of rare metals from

wastewater,¹⁶ friction control,¹⁷ organic electronics,¹⁸ and ₄₆ supported catalysis.¹⁹ 47

Many methods of surface functionalization have already 48 been reported. In an industrial environment, dry physical 49 methods are preferred over wet chemical grafting, as they do 50 not require the use of solvents. In this work, a chemical route is $_{51}$ chosen to obtain strong covalent bonds at the anchor points of 52 the targeted chains. Two strategies of chain grafting can be 53

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54 distinguished.²⁰ The grafting-to strategy allows for the 55 attachment of chains previously synthesized and functionalized 56 at one end. The functional groups react with the surface and 57 establish the desired covalent bond. The other strategy is 58 grafting-from, which permits the growth of chains after the 59 prior implementation of the initiator on the surface. Depend-60 ing on the grafting density, the chains tethered on the surface 61 by one end adopt different conformations and different 62 regimes can be defined.²¹ At low grafting densities, "mush-63 room" or "pancake" conformations are described depending on 64 the solvent quality. The coil dimension of the isolated tethered 65 chain in good or theta solvent conditions will be similar to that 66 of the ungrafted chains. In these conditions, the thickness of 67 the polymer layer is of the order of $2R_{\rm G}$ with $R_{\rm G}$ the radius of 68 gyration of the free polymer chain. With increasing graft 69 densities, chains will be obliged to stretch away from the 70 surface forming the brush-like conformation. Polymer brushes 71 are categorized into two groups differing in graft density: the 72 semidilute brush and the concentrated (or high-density) brush. 73 The crossover between the polymer chains in the semidilute ⁷⁴ regime and the concentrated regime has been observed for σ ~ 75 0.2-0.3 chain nm⁻², but for a specific system, the value may 76 depend on the size of the pendent groups.^{22,23} For each 77 solvation regime, specific scaling laws apply between the 78 thickness of the polymer layer, the size *a* of the monomer, and 79 the chain grafting density.²⁰ The grafting-to methods do not 80 reach high grafting densities to be achieved due to steric 81 hindrance. On the other hand, the grafting-from methods, 82 when carried out under controlled polymerization conditions, 83 i.e., with a progressive and simultaneous growth of the chains, 84 make it possible to obtain a high grafting density.

To achieve high chain grafting density, the grafting method 85 86 has to be chosen among surface-initiated controlled radical 87 polymerization (SI-PRC) also referred more recently to 88 surface-initiated reversible-deactivation radical polymerization 89 (SI-RDRP).^{7,24} In this work, Surface-initiated atom transfer 90 radical polymerization (ATRP) has been used as it is the most 91 popular for 20 years due to its versatility and its relative ease of 92 use.^{21,25,26} Conventional ATRP typically uses a transition-93 metal complex as the catalyst with an alkyl halide as the 94 initiator (R-X with X = Cl, Br, I) and various transition-metal 95 (Mt) complexes (Mt^{n+}/L), namely, those of Cu, Fe, Ru, Ni, 96 Os, etc., (with L: ligand) have been employed as catalysts for 97 ATRP. In an SI-ATRP process, the initiator is grafted onto the 98 surface. Then, the polymerization is conducted in a controlled 99 manner either in the presence of untethered sacrificial initiator 100 or in the absence of untethered sacrificial initiator but with 5-101 25 mol % of deactivator (Mt^{n+1}/L) with respect to the 102 activator (Mtⁿ⁺/L).^{27,28} Since the initial ATRP works, many 103 attempts have been made to lower or even suppress the ¹⁰⁵ amount of catalyst (often copper) used in ATRP. Among them ¹⁰⁵ are the metal-free ATRP^{29,30} or the externally controlled ¹⁰⁶ ATRP³¹ such as $eATRP^{32-34}$ or photoATRP³⁵⁻³⁷ being 107 controlled by electrical current or light, respectively.

In the SI-ATRP modification, the main drawbacks are the difficulty of analyzing the length of the polymer chains grafted no onto the surface as well as the grafting density. Using the hadove-mentioned scaling laws, measurements of polymer thickness in dry and solvated states can give access to the degree of polymerization and grafting density.^{38–40} However, the polymer coatings are analyzed by tedious or indirect methods. The grafted polymer chains can indeed be detached from the surface for analysis, after either destruction of the substrate or chain release by hydrolysis.⁴¹ Another method is 117 the analysis of the polymers obtained in solution, by the 118 activation of a sacrificial initiator introduced into the reaction 119 medium. In that case, it must be assumed that similar 120 mechanism and kinetics take place for the polymerization both 121 in solution and from the surface. This method is usually 122 considered a good check for polymerization control. In the 123 absence of untethered initiator, another possibility to maintain 124 the controlled polymerization is to add a sufficient 125 concentration of deactivator.²⁷ The advantage of this method 126 is the absence of free polymers produced in solution, which 127 could pollute the surface by adhesion. However, the degree of 128 polymerization and chain grafting density have then to be 129 directly determined. A new method requiring characterization 130 of the polymer layer in the dry state only is presented here for 131 that purpose.

The approach consists in performing polymerization on 133 crystalline silicon prisms and using quantitative IR spectros- 134 copy in attenuated total reflection (ATR) geometry. Then, 135 with a single measurement of the polymer layer thickness 136 (using ellipsometry or AFM), the grafting density, the length of 137 the polymer chains, their DP, and the fraction of active 138 tethered initiators can be directly obtained. Working with a 139 silicon prism providing multiple internal reflections (typically 140 ~20 reflections) gives the requested sensitivity.⁴²⁻⁴⁵ Silicon 141 prisms are commercially available and many (electro)chemical 142 strategies have been developed to graft organic moieties, such 143 as usual initiators, via Si–C or Si–O–C covalent linkages.^{46–48} 144 Finally, the IR configuration is well known at the prism 145 surface,49 allowing for quantitatively analyzing the IR bands 146 and determining the density and the orientation of the 147 molecules grafted to the prism.⁵⁰ Molecular densities as low as 148 ~0.15 nm⁻² have been determined, corresponding to ~0.1 ¹⁴⁹ equiv of one monolayer, providing the requested sensitivity to 150 determine practical initiator densities.⁵

Herein, the method is presented for the case study of high- 152 density polystyrene brushes synthesized using the SI-ATRP 153 procedure after initial grafting of the initiator onto the prism 154 surface. Three different routes of introduction of this initiator 155 via Si-C covalent bonds have been developed to modulate the 156 density of grafted initiators and assess the corresponding 157 impact on the styrene polymerization efficiency. The polymer- 158 ization of styrene has been conducted in classical ATRP 159 conditions, in the absence of untethered sacrificial initiator. 160 Kinetics studies assessing the control of the polymerization 161 process on silicon surface have been conducted in the initial 162 work of Matyjaszewski et al.²⁷ For polymerization in solution, 163 ethyl 2-bromoisobutyrate has been used as the initiator.^{52,53} In 164 such conditions, the polymerization was well controlled with 165 first-order kinetics, a linear increase of $M_{\rm p}$ with conversion and 166 molar mass dispersities D in the range 1.07-1.10.⁵⁴ 167

2. RESULTS AND DISCUSSION

2.1. Grafting of ATRP Initiator via Three Strategies. In 168 the first approach displayed in Figure 1A, well-defined 169 fl carboxydecyl-terminated silicon(111) surfaces have been 170 chosen as the starting state for the step-by-step covalent 171 grafting of the polymerization initiator for several reasons. 172 First, they are obtained by photochemical hydrosilylation of 173 10-undecylenic acid on hydrogenated silicon surfaces, leading 174 to a robust attachment of the alkyl chains via covalent Si–C 175 bonds.⁵⁰ Rather high density of acid chains can be achieved, 176 typically between 2 and 3 acid chains nm^{-2} , which is a key 177



Figure 1. Multistep chemical modification of crystalline silicon Si(111) surface (A) and the corresponding ATR-FTIR spectra in ppolarization after (B): the photochemical hydrosilylation of 10undecylenic acid on the etched SiH_x surface leading to the carboxyterminated surface, Si-acid (a); the activation of the acid functions via EDC/NHS (b); the amide bond formation by coupling the ester-NHS functions with initiator 1 in aqueous medium leading to Si-Br1 (c). Absorbance is computed with respect to the hydrogenated Si(111) surfaces.

178 parameter to obtain brush-like polymers on the surface.²¹ 179 Finally, the terminal carboxyl functions can be modified with 180 amino linkers in mild conditions using the well-known 1-ethyl-181 3-(3-dimethylaminopropyl)carbodiimide/*N*-hydroxysuccini-182 mide (EDC/NHS) coupling strategy.^{55–58} In this case, an 183 aminoethyl-substituted compound bearing an α -bromoisobu-184 tyryl moiety has been proposed as a polymerization initiator 185 (initiator 1) to be grafted on the surface via amide bonds.^{6,59} 186 Its synthesis as a hydrochloride salt has been realized in three 187 steps as described in the Experimental Section.⁶⁰

To characterize the immobilization of the initiator 1 directly 189 on the silicon surface, ATR-FTIR spectroscopy has been 190 performed using the modified silicon prism as the ATR 191 element. Figure 1B represents the IR spectra of the silicon 192 surface after each chemical modification: 10-undecylenic acid grafting (a), EDC/NHS activation (b), and amide bond 193 formation with initiator 1 (c). In either case, the reference 194 spectra are that of the freshly etched Si(111) surface 195 (abbreviated as SiH_x). Focusing on the 1500–1900 cm⁻¹ 196 spectral range, the carbonyl stretching mode ν CO of the 197 acid-terminated surface is clearly seen at 1715 cm⁻¹ and the 198 triplet band at ~1743 cm⁻¹ is characteristic of the ν CO modes 199 of the ester-NHS function of the activated surface. 200

After reaction of the ester-NHS groups with initiator 1, 201 spectrum (c) reveals the complete disappearance of the triplet 202 band and the presence of the two amide bands at 1650 and 203 1535 cm⁻¹, confirming the success of the initiator grafting. The 204 carbonyl peak is still present at a higher wavelength of ~ 1727 205 cm⁻¹ suggesting unreacted acid or partial hydrolysis of ester- 206 NHS functions during the aminolysis. To determine the yield 207 of the chemical modification of the grafted carboxydecyl 208 chains, we have developed quantitative tools from the 209 integrated absorbance of the carbonyl peaks measured for 210 the p- and s-polarization of the IR beam.^{50,61} Briefly, an IR 211 calibration using similar molecules (decanoic acid in dodecane 212 and N-succinimidyl palmitate in tetrahydrofuran, THF) is 213 performed at different concentrations to determine the 214 absorption cross-section of the carbonyl modes of the 215 carboxylic acid and the ester-NHS functions as explained in 216 supporting information, Section S-I. By comparing the 217 integrated areas of characteristic peaks with the corresponding 218 ones of the grafted molecules, two characteristic quantities $N_{//219}$ and $N_{\scriptscriptstyle \perp}$ can be computed. They are equivalent to a surface $_{220}$ concentration of molecules corresponding to the projection of 221 the dynamic dipole of the considered mode on the surface and 222 its normal, respectively. The actual areal density of the 223 carbonyl functions is deduced from the sum $N_{//}$ + $N_{_1}$, and the $_{224}$ number of grafted acid and ester-NHS chains per nm² can this 225 way be calculated. Table S1 summarizes the integrated 226 absorbance of the carbonyl peaks in p- and s-polarization of 227 the various modified surfaces, and Table 1 shows the 228 tl corresponding grafting density. Furthermore, an independent 229 IR calibration of dodecane has been achieved to determine the 230 surface concentration of methylene units in the grafted chains 231 through the analysis of the νCH_2 band chains. On 232 carboxydecyl layers, this calibration essentially yields the 233 same results as that based on the analysis of the ν C=O 234 band. A density of 2.3 \pm 0.4 grafted chains per nm² for the 235 carboxydecyl-terminated Si(111) monolayer is found, whereas 236 a density of 2 \pm 0.4 ester-NHS chains per nm² is obtained, 237 which corresponds to an activation yield of ~85%. In the case 238 of the Si-Br1 surface, a residual amount of $\sim 0.6 \pm 0.1$ acid 239 chains per nm² is calculated, given a total amidation yield of 240 ~70% with 1.7 \pm 0.3 bromoisobutyryl-terminated chains per 241 $\rm nm^{-2}.$ It means that ~20% of the surface Si atoms are linked to $\rm _{242}$

Table 1. Molecular Density N (in nm⁻²) at Various Modification Stages of Si(111) Surfaces, According to Strategies 1, 2, and 3

| | starting surface (from νCO or $\nu_{s}\text{CH}_{2}$) | | initiator-grafted surface (from $ u 	ext{CO})$ | polymerized surface (number of styrene units from $$\nu{\rm CH_{aro}}$)$ |
|------------|--|-------------------------|--|--|
| strategy 1 | Si-acid (from vCO/ ν_s CH ₂) | Si-ester NHS (from vCO) | Si-Br1 | Si-PS1 |
| | $2.3 \pm 0.4/2.6 \pm 0.5$ | 2 ± 0.4 | 1.7 ± 0.3^{a} | 11.6 ± 2.2 |
| strategy 2 | Si-ester (from v _s CH ₂) | | Si-Br2 | Si-PS2 |
| | 1.53 ± 0.3 | | 1.5 ± 0.3 | 54.2 ± 11 |
| strategy 3 | hydrogenated surface | | Si-Br3 | Si-PS3 |
| | no grafted molecule | | 0.9 ± 0.2 | 141 ± 28 |

^{*a*}Based on the determination of the surface concentration of residual acid groups.

 f_2

243 an initiator-terminated chain, a figure to be compared to the 244 grafting of ~50% of the surface Si atoms in the most dense 245 alkyl layers.⁶² The water contact angle of the three surfaces was 246 also measured: it rises from $61 \pm 1^{\circ}$ for the acid surface to 67 247 and $74 \pm 1^{\circ}$ after the NHS activation and amidation reaction, 248 respectively, confirming the grafting of nonpolar terminal 249 groups on the silicon surface.

250 As a second strategy, the commercially available α -251 bromoisobutyryl bromide (initiator 2) has been immobilized 252 on the Si surface via an ester linkage as depicted in Figure 2A.



Figure 2. Multistep strategy for the attachment of α -bromoisobutyryl initiator (initiator 2) via ester bonds (A) and their corresponding ATR-FTIR spectra in p-polarization at various stages of the attachment procedure (B): photochemical hydrosilylation of methyl 10-undecenoate on the SiH_x surface, Si-ester (a); reduction of the ester functions with LiAlH₄ (b) followed by a vacuum drying at 80 °C, Si-OH (b'); esterification of the hydroxyl functions with α -bromoisobutyryle bromide, Si-Br2 (c). Absorbance is computed with respect to the hydrogenated SiH_x surface.

253 Similar strategies have proven to be efficient for the growth of 254 brush-like polymer chains by SI-ATRP on various substrates 255 like silicon,^{27,63,64} polymers,^{65,66} and nanoparticles.^{7,24} The 256 surface modification involves three steps. The photochemical 257 hydrosilylation of methyl-10-undecenoate on SiH, leads to the 258 formation of the ester-decyl-terminated monolayer Si-ester. 259 Then, the ester groups are reduced in the presence of $LiAlH_4$ to form the hydroxyl-terminated surface Si-OH; the latter is finally esterified by reaction with initiator 2. Figure 2B shows 261 262 the IR-ATR spectra of the three different monolayers. From spectrum (a), a broad peak with a maximum at 1747 cm^{-1} is 263 attributed to the stretching mode of the ester function together 264 265 with a shoulder at 1724 cm⁻¹ related to the ν CO mode of the 266 carboxylic acid, suggesting the partial hydrolysis of the ester 267 groups into acid groups. Since the two carboxyl and ester peaks 268 overlap, their fitting is very sensitive to the width of their 269 bands. The quantification has therefore been focused on the 270 quantification of the v_cCH₂ mode from the alkyl chain to 271 extract an areal density of $\sim 1.53 \pm 0.3$ grafted chains per nm². 272 After reduction with LiAlH₄, spectrum (b) reveals the 273 complete disappearance of the acid and ester functions and $_{\rm 274}$ the appearance of a broad peak at 1653 $\rm cm^{-1}$ maybe due to 275 entrapped water molecules (δ_{H2O} scissor mode) interacting by

hydrogen bonding on the hydroxylated surface. Heating at 80 276 °C under vacuum does not remove the presence of this peak 277 but favors the oxidation of the surface as unveiled on the IR 278 spectrum (b') with a broad peak at 1040 cm⁻¹ corresponding 279 to the silicon oxide vibrations. In the last spectrum (c), the 280 peak related to the ν CO of the ester becomes again visible and 281 shifted to 1739 cm⁻¹, attesting to the successful attachment of 282 initiator 2. The surface Si-Br2 is further oxidized. The oxide 283 thickness can be estimated from the intensity of the band at 284 1040 cm⁻¹ related to the transverse optical phonon vibration in 285 s-polarization (in this case, 2.3 mAbs, data not shown). As 1 286 mAbs corresponds to a thickness of ~1.5 Å, a 3.4 Å-thick oxide 287 film is estimated.⁶⁷ To avoid interference with the residual 288 peak at 1720 cm⁻¹ present after the vacuum heating treatment, 289 the quantitative analysis of the ester peak was performed on 290 spectrum (c) by taking the spectrum (b') as the reference 291 spectrum (Figure S6). For the quantification of grafting density 292 of the Si-Br2 surface, IR calibration of undecenyl isobutyrate 293 (initiator 3) has been realized as explained above. A density of 294 1.49 ± 0.3 initiator-terminated chains per nm⁻² is calculated, 295 yielding to a quantitative conversion of the initial ester chains 296 within the accuracy of the molecular density determination. 297 From ellipsometry analysis, the thickness of the layer amounts 298 to 1.4 nm, close to the calculated thickness of 1.48 nm with a 299 tilt angle of 30-35° (determined by Chemdraw software). 300 However, the actual geometry of the chains appears to depart 301 from this ideal picture, in which the orientation of the C=O $_{302}$ bond is expected to be $\sim 60^{\circ}$ off the surface normal. Identifying 303 the C=O bond direction to the orientation of the dynamic 304 dipole of the stretching C=O bond, the corresponding 305 average orientation of the C=O can be experimentally 306 determined as $\tan^{-1}[(N_{//}/N_{\perp})^{1/2}]$, which yields a value of $_{307}$ $\sim 38^{\circ}$. Infrared data therefore suggest the presence of 308 conformational defects like gauche conformers in the grafted 309 layer. A possible explanation of this departure from an ideal 310 configuration can be thought of as arising from the 311 intermediate SiOH surface. The presence of hydroxyl 312 termination could induce some chain pairing through the 313 mediation of water molecules, to favor the buildup of an 314 energetically favorable hydrogen-bond network. The presence 315 of strongly bound water molecules evidenced in the infrared 316 spectra supports this hypothesis. The induced chain pairing 317 favors the presence of gauche conformation in typically half of 318 the grafted chains. By assuming that this conformation does 319 not change in the final esterification step, an average 320 orientation of the C=O bonds of $\sim 30^{\circ}$ with respect to the 321 surface normal is expected, in typical agreement with the low 322 value experimentally determined. In any case, infrared data 323 reveal the presence of a significant conformational disorder on 324 top of the grafted layer. 325

The last strategy consists in grating initiator 3 (an alkenyl 326 chain terminated with a bromoisobutyrate head) on a 327 hydrogenated silicon surface. Initiator 3 was synthesized in 328 one step with excellent yield from the esterification of 10- 329 undecenol with α -bromoisobutyryl bromide (initiator 2).⁵⁷ 330 The hydrosilylation reaction was performed thermally to avoid 331 competitive homolytic C–Br bond cleavage when using UV 332 irradiation. Figure 3 represents the ATR-IR spectrum of 333 f3 initiator 3 grafted on Si(111), Si-Br3. The presence of the 334 stretching modes of the alkyl chains at 2860 and 2925 cm⁻¹ 335 together with their bending mode at 1465 cm⁻¹ and the 336 stretching mode of the ester link at 1735 cm⁻¹ confirms the 337



Figure 3. ATR-FTIR spectrum in p-polarization after the direct thermal hydrosilylation of initiator 3 on the SiH_x surface. Absorbance is computed with respect to the hydrogenated SiH_x surface.

338 grafting of initiator 3 on the surface. The stretching and the 339 bending mode of the methyl groups are also observed at 2965 340 and 1265 cm⁻¹, respectively. In parallel, the surface Si-Br3 is 341 quite oxidized with an oxide peak absorbance of 2.6 mAbs in s-342 polarization at ~1050 cm⁻¹, corresponding to an equivalent 343 oxide thickness of 3.9 Å.

For the quantification of the ester peak, an IR calibration of sts initiator 3 has been realized in CDCl_3 at various concentrations (cf. Section S-I). A density close to 0.9 ± 0.2 initiator terminated chains per nm² is calculated. This value is low (3 stimes lower than that of closely packed alkyl layers on Si(111) sty and significantly lower than the value obtained using the first sto strategy). The successful grafting was also evidenced by X-ray photoelectron spectroscopy (XPS). The C 1s core-level spectrum (Figure 4A) is separated into four main contributions at 284.3 eV related to a carbon linked to Si (C–Si), at 285.1 step eV attributed to sp3 carbon only linked to C or H atoms sts (Csp3), at 286.6 eV to carbon linked to bromine or the

f4

terminal carbon of an alkyl chain linked to the oxygen atom 356 from an ester group, and finally at 289.1 eV to the carbon of an 357 ester function (C-ester). From the quantitative analysis of the 358 normalized areas of these contributions (Table S4), the ratio of 359 Csp3/C-ester can be determined and is perfectly equal to 11, 360 as expected for surface species Si-CH₂-(CH₂)₉-CH₂-OOCC- 361 $(CH_3)_2$ Br. However, the ratio C-ester/C-Si is twice smaller as 362 expected (~0.47 instead of 1). Part of this low value can 363 actually arise from the attenuation of the photoemitted 364 electrons by the surface organic layer since the Si-C bonds 365 are located at the bottom of the layer, whereas ester groups are 366 located at the top. On the basis of the attenuation of a $C_{16}H_{33}$ 367 layer, 68 a transmission coefficient of ~0.67 can be estimated for 368 the organic layer, which might account for the about half of the 369 discrepancy with the expected value of the Si-C contribution 370 to the C 1s band. Another possible origin for this discrepancy 371 can be paralleled with the value of the C-Br, C-O/C-ester 372 contribution ratio, which is equal to 2.5 instead of 2. Since the 373 surface is strongly oxidized with a characteristic contribution at 374 ~103.0 eV in the Si 2p XPS spectrum (Figure S7), it can be 375 suggested that part of the initiator 3 molecules have reacted 376 with surface SiOH species generated during the reaction upon 377 surface oxidation by residual water. Even though the detailed 378 mechanism remains to be clarified, the generation of some Si- 379 $O-(CH_2)_{11}-OOCC(CH_3)_2Br$ species at the surface is con- 380 sistent with a decrease in the expected Si-C contribution and 381 an increase of that of C-Br, C-O to the C 1s band. To put in 382 another way, some grafting may also occur via Si-O-C 383 linkage. The overlap of the various contributions to the C 1s 384 band makes uncertain the accurate determination of the 385 respective proportions of the chains grafted through a Si-C 386 bond to that grafted through a Si-O-C bond. The data are 387 consistent with a proportion of molecules grafted through Si- 388 O-C bonds up to 50%. Finally, the Br 3d core-level spectrum 389 is fitted using two spin-orbit splitting doublet located at ~70.5 390 eV (Br $3d_{5/2}$) and ~71.4 eV (Br $3d_{3/2}$), attributed to Br-C 391 bounds and a second at ~69.4 eV (Br $3d_{5/2}$) and ~70.4 eV (Br $_{392}$ $3d_{3/2}$) given by negatively charged Br, which forms during 393 exposure to the X-ray beam (Figure 4B).⁶⁹ From the 394



Figure 4. XPS spectra of the direct thermal hydrosilylation of initiator 3 on SiH_x surface: in the C 1s (A) and Br 3d (B) regions. The normalized areas of the contributions to C 1s are 3.2% for O=C-O, 8.2% for C-Br/C-O, 35.3% for Csp3, and 1.5% for Si-C (see Section S-II and Table S4).

³⁹⁵ ellipsometry analysis, the thickness of the film is evaluated to ³⁹⁶ 1.7 nm, a much higher value than those obtained in the ³⁹⁷ indirect strategy for the preparation of Si-Br1 and Si-Br2. ³⁹⁸ However, this value is close to those reported for monolayers ³⁹⁹ with such types of initiators.^{24,70} The contact angle of Si-Br3 is ⁴⁰⁰ 75 ± 1°, which is close to the value of Si-Br1. Noteworthy, the ⁴⁰¹ infrared data give an average orientation of the C=O bond ⁴⁰² (determined from the $N_{//}/N_{\perp}$ ratio) close to 53° off the surface ⁴⁰³ normal. This is compatible with a geometry of the grafted ⁴⁰⁴ chains close to an ideal all-trans conformation (which would ⁴⁰⁵ yield a value of ~60°), regardless of the attachment to the ⁴⁰⁶ surface achieved through Si−C or Si−O−C bonds.

2.2. SI-ATRP of Styrene. For the polymerization of styrene 408 on the surface, no sacrificial initiator is needed but an excess of 409 deactivator CuBr₂ was added with (monomer)/(CuBr)/ 410 (CuBr₂)(PMDETA) = 100/1/1/1.2 molar ratio. The same 411 polymerization conditions were used on the three types of 412 initiator functionalized surfaces: Si-Br1 and Si-Br2 afforded 413 from the two-step strategy using acid or ester-terminated 414 monolayer as primary anchoring layer, respectively, and Si-Br3 415 obtained by the direct grafting of initiator 3 on the pristine 416 SiH_x surface. A final rinse using a Soxhlet in dichloromethane 417 for 24 h is mandatory to remove physisorbed polystyrene 418 formed in solution. Figure 5 displays the ATR-FTIR spectra in



Figure 5. ATR-FTIR spectra in p-polarization of Si(111) surfaces modified with polystyrene chains, Si-PS1 (spectrum a) starting from Si-Br1, Si-PS2 (spectrum b) starting from Si-Br2, and Si-PS3 (spectrum c) starting from Si-Br3. Absorbance is computed with respect to the hydrogenated SiH_x surfaces.

⁴¹⁹ p-polarization of three polystyrene-modified Si surfaces, (a) Si-⁴²⁰ PS1 (b) Si-PS2, and (c) Si-PS3 obtained from Si-Br1, Si-Br2, ⁴²¹ and Si-Br3, respectively. In either case, the main peaks related ⁴²² to the polystyrene formation are observed: the stretching ⁴²³ modes of the C–H from the benzene ring between 3003 and ⁴²⁴ 3084 cm⁻¹, the strong IR active ring stretch vibrations for ⁴²⁵ which the CH group moves essentially as a unit at 1604 cm⁻¹ ⁴²⁶ (quadrant stretch mode), 1492 cm⁻¹ (semicircle stretch ⁴²⁷ mode); at 1453 cm⁻¹ the observed band results from the

contribution of a semicircle stretch mode of the benzene ring 428 and that of the in-plane deformation mode of the methylene 429 units of the polymer chain.^{71,72} Other less-intense vibrations 430 related to the polystyrene chains are revealed in spectra (b) 431 and (c): the symmetric and asymmetric stretching νCH_2 432 modes of the methylene chains at 2850 and 2924 cm⁻¹, the 433 overtone/combination bands of the monosubstituted benzene 434 ring in the 1800-1945 cm⁻¹ range. Further contributions at 435 1330 cm⁻¹ (sextant stretch mode of the ring mixed with a CH 436 in-plane bending mode) and 1311 cm⁻¹ (centrosymmetric CH 437 in-plane bending mode) are also found. By comparing spectra 438 (b) and (c), the IR band intensities are much larger in the case 439 of the Si-Br3 surface (spectrum c) than in the case of the Si- 440 Br2 surface (spectrum b), by a factor of 2.5–2.8 for the two 441 sharp peaks at 1455 and 1493 cm^{-1} . New peaks are also 442 revealed at 1028, 1155, and 1180 cm^{-1} , a mode mixing ring 443 quadrant stretch and in-plane CH bending, the in-plane 444 bending mode of the CH group in para position, and a 445 combination band involving out-of-plane CH deformation 446 modes, respectively. On the contrary, the two bands related to 447 Si-O-Si vibrations are rather similar in all spectra, arising 448 from an oxide layer whose thickness is estimated to be close to 449 ca. 6.5-7.5 Å. This strong oxidation may be induced by the 450 presence of the copper metal at 100 °C on the silicon 451 surface.73 452

From this analysis, the styrene polymerization seems to be 453 much more efficient when starting from Si-Br3, than from Si- 454 Br2 and even more than from Si-Br1. At first glance, this result 455 may be related to the different densities of the grafted initiator 456 chains (0.9 nm^{-2} for Si-Br3 vs 1.5 nm^{-2} for Si-Br2 and 1.7 457 nm^{-2} for Si-Br1), a lower steric hindrance favoring the growth 458 of PS chains on the surface. In either case, the initiator density 459 is much higher than the density of brush polymers typically up 460 to 0.4 nm^{-2, 22,38} Other factors are also plausible. For instance, 461 it has been seen that the chain conformation is more ordered 462 on SiBr3 than on SiBr2; the conformational disorder on SiBr2 463 could be less favorable to polymerization. Moreover, though 464 the density of grafted initiator is rather similar between Si-Br1 465 and Si-Br2, the polymerization is inefficient on the Si-Br1 466 surface. Indeed, a slight increase of the two $\nu_{sa}CH_2$ bands 467 corresponding to the methylene (CH_2-CH_2) groups is visible 468 when the spectrum of the Si-Br1 surface is taken as a reference 469 (cf. Figure S8). Their intensities are quite low (<0.5 mAbs) 470 compared to those of the carbonyl and alkyl peaks, suggesting 471 the growth of a few polystyrene chains at the surface 472 corresponding to a surface concentration in styrene units of 473 a few monolayers only. Although many optimizations were 474 attempted (i.e., increase of the reaction time, temperature 475 change, use of various ligands...), styrene cannot be efficiently 476 polymerized by SI-ATRP on Si-Br1 surface. A possible 477 explanation is that the two nitrogen atoms present in Si-Br1 478 may complex with the Cu catalyst inhibiting the ATRP 479 polymerization. 480

The morphology of Si-PS2 and Si-PS3 polystyrene layers 481 were then investigated by AFM (Figure 6) and their thickness 482 f6 was measured by locally removing the organic layer. In both 483 cases, the images reveal a homogeneous coverage of the surface 484 by a dense and homogeneous layer (Figure 6a,b) but with 485 different thicknesses: ~11 nm for the Si-PS2 layer and ~29 nm 486 for Si-PS3 (Figure 6c,d). These values are in good agreement 487 with those deduced from ellipsometry measurements (9 nm for 488 Si-PS2 and 27 nm for Si-PS3). They are furthermore consistent 489 with the relative intensity of the polystyrene IR bands 490



Figure 6. AFM characterization of the Si-PS2 (left column) and Si-PS3 (right column) polystyrene layers. (a, b) Top-view images of the layers. The inset in (a) shows a higher-magnification one of the 3D aggregate found atop the layer. Note its characteristic \sim 15 nm height corresponding to twice the thickness of the layer and its structure corresponding to an assembly of smaller structures. (c, d) Top-view images and cross sections at the frontier between the silicon substrate and the polystyrene layer. (e, f) Height distributions corresponding to images (e) and (f) give the mean thickness of the layers: \sim 11 nm for Si-PS2 and \sim 29 nm for Si-PS3.

491 corresponding to these two layers (greater intensity of the IR 492 bands for the thicker Si-PS3 layer). In the case of the Si-PS2 493 layer, the images also reveal the presence of a low density $_{494}$ (~ 10^8 /cm²) of three-dimensional (3D) aggregates with 495 characteristic sizes (~15 nm height and a few hundred nm 496 width) atop the layers (Figure 6a, inset). These aggregates look 497 like assemblies of smaller structures with size comparable to 498 those found in the underneath layer. Their height, about twice 499 as large as the layer thickness, suggests they might be also 500 polystyrene chains aggregated atop the layer. From their volume (assuming a spheroid shape) and their density, the 501 502 amount of matter corresponding to these aggregates may be 503 roughly calculated. An equivalent thickness of ca. 3-4 nm is 504 found. Such aggregates are not observed for the Si-PS3 layer. 2.3. Quantification of the Polymer Brushes. To get 505 506 quantitative information about the number of grafted PS 507 chains, an IR calibration of polystyrene in solution was 508 performed to convert the absorbance of the peaks character-509 istic of PS into the areal density of the PS chains. For this, 510 ATR-FTIR spectra of polystyrene were measured at different 511 concentrations in CDCl₃ in s-polarization as presented in 512 Figure S9 and the magnitude of the sharp peak at 1493 cm⁻¹ is

used for determining the areal density of styrene units, as 513 detailed in Sec S-I and S-III. From these results, the surface 514 concentration of styrene units was derived: $11.6 \pm 2.2 \text{ nm}^2$ for 515 Si-PS1, 54.2 \pm 11 nm⁻² for Si-PS2, and 141 \pm 28 nm⁻² for Si- ₅₁₆ PS3. To obtain the density of grafted PS chains, the degree of 517 polymerization (DP) is needed. This piece of information can 518 be derived from the thickness of the polymer layer. Polymer 519 chains densely grafted at a surface (polymer brushes) usually 520 adopt a collapsed and less organized structure where the chains 521 are not so well oriented and fully extended, in contrast to 522 ordered monolayers of grafted molecules such as that of the 523 SiBr3 surface. Considering a brush without solvent (bulk 524 state), the thickness L of the polymer brush only depends on 525 DP and obeys a scaling law $L \sim DP^{2/3}$.²⁰ In this case, the 526 thickness of the polymer brushes is normalized to the average 527 distance a between two monomer units along a polystyrene 528 chain (~0.25 nm), leading the following scaling law L/a = 529 $DP^{2/3}$. Starting from a polymer thickness of 8.6 nm (SiPS2) or 530 26.3 nm (SiPS3), a DP of ~200 (SiPS2) or ~1000 (SiPS3) is 531 derived from the scaling law. This yields a fraction of active 532 initiators of 18 and 15% for SiPS2 and SiPS3, respectively. We 533 did not attempt a similar analysis for SiPS1 since, as mentioned 534 535 above, the polymerization efficiency is poor for this 536 configuration.

The initiation efficiency then appears similar for SiPS2 and 537 538 SiPS3, in spite of the distinct features of the SiBr2 and SiBr3 539 surfaces in terms of initiator areal density and conformational 540 ordering. On the contrary, the conversion obtained by starting 541 from SiBr3 appears significantly higher than that obtained 542 when starting from SiBr2, as reflected by the differences in the 543 areal density of styrene units measured by infrared spectros-544 copy. Since in either case polymerization is performed in the 545 same experimental conditions, this difference reveals that 546 polymerization kinetics are hindered to a larger extent when 547 starting from SiBr2 than when starting from SiBr3. This kinetic 548 limitation likely comes from steric hindrance (higher areal 549 concentration of active initiators for SiPS2), or from the 550 conformational disorder of the SiBr2 surface, as revealed by 551 infrared spectroscopy, or from both origins. Experiments using 552 mixed layers obtained by grafting of 10-undecen-1-yl-2-bromo-553 2-methylpropionate diluted in 1-decene at variable concen-554 trations are under consideration for addressing this issue.

These results point to the fact that differences in the density 556 or conformation of tethered initiators at the surface do have 557 consequences in terms of polymerization efficiency. Such 558 differences would not appear in the usual approach where the 559 bulk polymers resulting from the addition of untethered 560 initiators are analyzed. Therefore, a method such as that 561 proposed here offers a much more relevant and reliable picture 562 of the tethered polymer. In addition, the fraction of active 563 initiators is also obtained.

3. CONCLUSIONS

564 For the first time, ATR-FTIR quantification together with 565 AFM imaging offers an alternative to the indirect classical 566 methods (ie. using sacrificial initiators or detaching the grafted 567 polymers) to directly evaluate the DP of grafted brush 568 polymers and the surface density and the proportion of active 569 initiators. Three high-density polymer brushes were grafted 570 onto ATR silicon prisms and quantitative IR spectroscopy was 571 used to monitor the grafting of ATRP initiators and compare 572 the polymerization efficiency. Grafting densities of polymer-573 ization initiators ranged 0.9–1.7 molecules nm⁻². To obtain polymer brushes, the ATRP polymerization of styrene was 574 575 then carried out without sacrificial initiators in the presence of 576 CuBr₂ and a constant monomer concentration. Polymerization 577 efficiency was assessed by measuring the areal concentration of 578 polymerized styrene units. Obtained values fell in the range of 579 12–141 styrene units nm^{-2} . The lowest value corresponds to 580 the grafting of polymerization initiators through amino linkers. 581 The complexing affinity of these linkers with the reaction 582 catalyst plausibly favors the dormant species at the expense of 583 the active radical species in the ATRP process. In the absence 584 of such an effect, polymerization is efficient and DP in the s85 range of 200-1000 is obtained from the measurement of the 586 polymer thickness and a scaling law (valid for a brush without 587 solvent) relating it to DP. The efficiency of the grafted 588 initiators is found to be in the range of 15–18%, independently 589 of the initiator grafting density. In contrast, the polymerization 590 kinetics are lowered by steric hindrance or conformational 591 disorder in the layer of grafted initiators. The present approach 592 of combining ATR-FTIR quantification together with AFM 593 imaging to obtain a full characterization of polymer brushes is 594 directly generalizable to any polymer system and any ATRP 595 methods. It appears more relevant than classical methods

based on the analysis of bulk polymers obtained by adding 596 untethered initiators to the polymerization solution. It offers an 597 alternative to the analysis of the brush swelling ratio and 598 further provides the proportion of active initiators. We aim at 599 using such a full characterization of such polymer brushes for 600 applications in asymmetric catalysis.^{54,74} Such a detailed 601 characterization is of paramount importance to optimize the 602 loading of active species and finely tune their further chemical 603 reactions in a controlled way. Moreover, for the purpose of 604 multicatalysis, the extension of the present method to 605 copolymers is forecasted, notably to obtain information on 606 the rate of incorporation of different monomer units. On this 607 basis, a composition-property study can be seriously 608 considered.

4. EXPERIMENTAL SECTION

4.1. Materials. All purchased chemicals were of reagent grade or 610 higher (for all modifications on silicon substrate) and, if not 611 mentioned explicitly, used without further purification. Undecylenic 612 acid (99%) and undecylenic acid methyl ester (99%) were purchased 613 from Acros Organics. 10-Undecen-1-ol (98%), N-(3-dimethylamino- 614 propyl)-N'-ethylcarbodiimide (EDC, 98%), N-hydroxysuccinimide 615 (NHS, commercial grade), ethyl 2-bromoisobutyrate (EBiB, 99%), α - 616 bromoisobutyryl bromide (98%), N,N,N',N",N"-pentamethyldiethy- 617 lenetriamine (98%) (PMDETA), Bipy (2,2'-bipyridyl, 99%), pyridine, 618 copper(II), and copper(I) bromide (98%), and styrene (99%) were 619 purchased from Sigma-Aldrich. The cleaning reagents [hydrogen 620] peroxide 30%, sulfuric acid 96%, glacial acetic acid, tetrahydrofuran 621 (THF), dichloromethane (DCM), acetonitrile (ACN)] and the 622 etching reagent (hydrofluoric acid, HF, 50%) were of RSE quality and 623 supplied by Carlo Erba. Diethylether was distilled over LiAlH₄, 624 methanol was distilled from Mg, THF was distilled from sodium/ 625 benzophenone, and dichloromethane and hexane were distilled from 626 CaH₂ before use. Molecular sieves 4 Å used in reaction were dried 627 overnight at 500 $^\circ\text{C}$ then placed in a Schlenk tube under argon. $_{628}$ Copper(I) bromide (CuBr, 98%) was purified with glacial acetic acid, 629 washed with ethanol and diethylether, and stored under argon. 630 Styrene was passed through a basic alumina gel column to remove 631 traces of inhibitor. Ultrapure water UPW (Milli-Q, 18.2 MΩ•cm, at 632 25 °C) was used to prepare aqueous solutions and for rinsing. The 633 silicon samples were cleaved from double-side-polished n-type silicon 634 ((111), FZ, 30-40 Ω cm, Siltronix, France). They were glued with wax 635 between two 45° machined aluminum blocks (see the Supporting 636 Information, SI for more details), then both sample edges were 637 mechanically polished with carborundum abrasive paper (from grit 638 240 to 1200). In a last step, both faces were polished with diamond 639 paste of decreasing grain sizes (3 and 1 μ m) until shining bevels are 640 obtained. Each prism is accurately measured for the quantitative 641 analysis. The typical size of a silicon prism is $20 \times 13 \times 0.5$ mm and a 642 bevel angle of 46°, giving \sim 25 reflections.⁴ 643

4.2. Syntheses of Initiators. 4.2.1. Initiator 1: N-(2-Amino- 644 ethyl)-2-bromo-2-methylpropanamide Hydrochloride. The initiator 645 is obtained in three steps: (1) Synthesis of tert-butyl (2-aminoethyl)- 646 carbamate: A solution of di-tert-butyl dicarbonate (5.45 g, 25 mmol) 647 in 1,4-dioxane (7 mL) was added dropwise into a solution of 648 ethylenediamine (5 mL, 74.8 mmol) in 1,4-dioxane (50 mL). The 649 solution was stirred at room temperature for 17 h. A white precipitate 650 was filtered and the solution was concentrated under reduced 651 pressure. The solid was solubilized in water (110 mL) and the white 652 precipitate was filtered off. The solution was saturated with NaCl and 653 extracted with DCM (3×60 mL). The compound was isolated as a 654 pale yellow oil (1.9 g, 48%). ¹H NMR (300 MHz, $CDCl_3$): δ = 1.35 655 (s, 9H, tBu), 1.57 (s, 2H, NH₂), 2.66 (t, J = 6.0 Hz, 2H, CH₂NH₂), 656 3.04 (q, J = 6.0 Hz, 2H, CH₂NHBoc), 5.45 (brs, 1H, N<u>H</u>); (2) 657 Synthesis of tert-butyl 2-(2-bromo-2-methylpropanamido)- 658 ethylcarbamate: α-bromoisobutyryl bromide (1.8 mL, 14.6 mmol) 659 was added dropwise to a cooled (0 °C) solution of tert-butyl-(2- 660 aminoethyl)carbamate (1.57 g, 9.8 mmol) in CH₂Cl₂ (25 mL) and 661

662 triethylamine (5.8 mL). The reaction solution was stirred at room 663 temperature overnight and then poured into crushed ice (100 mL). 664 The compound was extracted with DCM (3 \times 100 mL). The 665 combined organic phases were washed with water, aqueous saturated 666 NaHCO3 solution, and water, dried over anhydrous MgSO4, and 667 concentrated by vacuum. The solid was purified by flash 668 chromatography on silica gel with ethyl acetate/petroleum ether 669 (1/2.5) as elution solvent and the product was isolated as an orange 670 powder (2 g, 56%). ¹H NMR (250 MHz, CDCl₃): δ = 1.34 (s, 9H, 671 tBu), 1.86 (s, 6H, BrC(CH₃)₂), 3.26 (m, 4H, CH₂CH₂), 5.42 (brs, 672 2H, NH); (3) Synthesis of N-(2-aminoethyl)-2-bromo-2-methylpro-673 panamide hydrochloride: tert-butyl 2-(2-bromo-2-674 methylpropanamido)ethylcarbamate (330 mg, 1.07 mmol) was 675 dissolved in a 1 M solution of HCl in ether (10 mL). The solution 676 was stirred at room temperature overnight. The white precipitate was 677 filtered off and washed with cold diethylether. The hydrochloride was 678 afforded (150 mg, 57%) as a white powder. ¹H NMR (300 MHz, 679 D₂O): δ = 1.86 (s, 6H, BrC(C<u>H</u>₃)₂), 3.10 (m, 2H, C<u>H</u>₂NH₃⁺), 3.47 680 (m, 2H, C<u>H</u>₂NH).

4.2.2. Initiator 3: 10-Undecen-1-yl-2-bromo-2-methylpropio-682 nate. 10-Undecen-1-yl-2-bromo-2-methylpropionate was synthesized 683 from 10-undecen-1-ol (8.3 mL, 41 mmol in 41 mL of dry THF) 684 cooled at 0 °C, by the addition of α-bromoisobutyryl bromide (5.1 685 mL, 41 mmol) and pyridine (3.5 mL, 43 mmol). The reaction mixture 686 was stirred for 3 h under argon, then n-hexane (25 mL) was added to 687 the reaction. The resulting solution was washed with HCl (2 M) (2 × 688 50 mL) and H₂O (2 × 50 mL) and dried over anhydrous Na₂SO₄. 689 The solvent was removed under reduced pressure to give the product 690 as a colorless liquid (13 g, 94%). ¹H NMR (250 MHz, CDCl₃): δ = 691 1.20-1.44 (m, 12H, CH₂); 1.62-1.75 (m, 2H, CH₂-CH₂O); 1.94 (s, 692 6H, BrC(CH₃)₂); 2.05 (q, *J* = 7,0 Hz, 2H, CH₂-CH₂=CH); 4.17 (t, *J* 693 = 9,0 Hz, 2H, CH₂CH₂O); 4.9-5.05 (m, 2H, CH₂=CH); 5.72-5.9 694 (m, 1H, CH₂=C<u>H</u>).

4.3. Silicon Surface Modifications. *4.3.1. Preparation of Hydrogenated Silicon Surfaces (SiH_x).* The silicon prism was cleaned ⁶⁹⁷ in a piranha solution (1:3 H_2O_2/H_2SO_4) at 100 °C for at least 2 h. ⁶⁹⁸ After thorough rinsing with UPW, the prism was immersed for 5 s in a ⁶⁹⁹ poly(tetrafluoroethylene) (PTFE) beaker filled with a 50% hydro-⁷⁰⁰ fluoric acid solution, then rinsed with UPW in a beaker for 5 s. The ⁷⁰¹ SiH_x surface was dried in a flow of N₂.

4.3.2. Photochemical Grafting of Acid- or Methyl Ester-703 Terminated Alkyl Monolayers on the SiH_x Surfaces. Undecylenic 704 acid (UA) or 10-methyl undecenoate (MeU) was outgassed under 705 argon in a Schlenk tube at 100 °C for 30 min and then cooled to 706 room temperature. The freshly prepared SiH_x prism was then 707 transferred into the Schlenk tube with continuous argon bubbling for 708 15 min. The Schlenk was hermetically closed and irradiated for 3 h in 709 a UV reactor (6 mW·cm⁻², 312 nm). The functionalized acid-710 terminated surface (Si-acid) was cleaned twice with glacial acetic acid 711 under argon bubbling at 75 °C for 15 min in a Schlenk tube and, 712 finally dried under N₂. For the ester-terminated surface (Si-ester), the 713 prism was washed thoroughly with copious amounts of acetone to 714 remove the residual ω -unsaturated alkyl ester and dried under N₂.

4.3.3. Activation of Si-Acid with EDC/NHS. Two solutions of 10 716 mM EDC and NHS were separately prepared in UPW at 4 °C. A 717 Schlenk tube was immersed in a water bath with a temperature 718 between 15 and 18 °C. An equal volume (5 mL) of EDC and NHS 719 was added into the Schlenk tube and flushed with argon for 10 min 720 before adding the acid-terminated silicon surface (Si-acid). For 90 721 min, the Schlenk tube with the prism was bubbled with argon, while 722 the temperature was controlled to be maintained in the range 723 mentioned above. Next, the prism Si-ester NHS was cleaned for 5 min 724 in a beaker with UPW, then rinsed copiously with UPW, and dried 725 under N₂.

4.3.4. Aminolysis of Initiator 1 on Si-Ester NHS. A fresh solution r27 of initiator N-(2-aminoethyl)-2-bromo-2-methylpropanamide hydror28 chloride at a concentration of 20 mM in UPW was prepared; the pH r29 was adjusted to 8.5–9 with 0.1 M NaOH solution. The solution was r30 then bubbled in a Schlenk tube with argon for 5 min before the freshly r31 activated prism was added. The argon bubbling was continued for 10 more minutes before the values of the Schlenk were closed. After 3 h, 732 the prism was cleaned for 2 min with THF and 2 min with DCM 733 followed by a final short rinse in UPW before drying the prism Si-Br1 734 under a flow of N_2 . 735

4.3.5. Reduction of Si-Ester with LiAlH₄. Diethylether (100 mL) 736 was added to a dried Schlenk tube, previously purged with argon. 737 About 5 g of LiAlH₄ powder was added slowly into the tube under 738 stirring. The Si-ester prism was then immersed in the solution. The 739 reaction mixture was kept at room temperature for 2 h. The modified 740 prism was taken out from the reaction mixture and washed thoroughly 741 with acetone, 0.5 M HCl solution, acetone, and UPW, sequentially. 742 The prism Si-OH was then dried by pumping under reduced pressure 743 for about 10 h and also at 80 $^{\circ}$ C under reduced pressure. 744

4.3.6. Esterification of Si-OH with α -Bromoisobutyryl Bromide. 745 The prism Si-OH was placed in a solution of 1.5 mL of pyridine in 50 746 mL of dry diethylether, followed by dropwise addition of 2 mL of α - 747 bromoisobutyryl bromide in 30 mL of dry diethylether over a period 748 of 30 min. The reaction mixture was gently stirred at 0 °C for 2 h and 749 then at room temperature overnight. The prism was taken out and 750 washed with ethanol and water followed by a Soxhlet in DCM 751 overnight. The prism Si-Br2 was then dried under N₂. 752

4.3.7. Grafting of Initiator 3 (10-Undecen-1-yl-2-bromo-2-753 methylpropionate) on Silicon Surface. The freshly HF-etched 754 silicon prism was transferred into the Schlenk containing neat 10-755 undecen-1-yl-2-bromo-2-methylpropionate, previously bubbled with 756 argon in a Schlenk tube for 30 min. Bubbling was maintained for 15 757 min. The Schlenk is hermetically closed and heated at 180 °C 758 overnight. After the reaction, the prism Si-Br3 was washed 759 ultrasonically with CH_2Cl_2 , anhydrous ethyl alcohol, and UPW 760 sequentially, each with 60 mL of solution for 3 min, respectively, and 761 dried N₂.

4.3.8. Surface-Initiated Polymerization of Styrene on Silicon 763 Surface. Polymerizations were performed using a mix of (monomer)/ 764 (CuBr)/(CuBr₂)(PMDETA) = 100/1/0.05/1.2 molar ratio in a 765 Schlenk tube at 100 °C. In a typical experiment for the preparation of 766 PS brushes, the following amounts were used: styrene (4.36 mL, 38 767 mmol, 100 equiv), PMDETA (91 μ L, 1.2 equiv), CuBr (55 mg, 1 768 equiv), and CuBr₂ (4.25 mg, 5 mol %), then the initiator-modified 769 surface (Si-Br) was immersed in the medium, and the solution was 770 degassed (three freeze-pump-thaw cycles) and back-filled with 771 argon, and the reaction was allowed to proceed for 17 h at 100 °C. 772 After polymerization, the silicon prism was purified by multiple 773 washings with toluene, acetonitrile, and CH₂Cl₂, and a Soxhlet was 774 carried out for 24 h in dichloromethane, then the prism was dried 775 under nitrogen. 776

4.4. Instrumentation. 4.4.1. Nuclear Magnetic Resonance 777 (NMR). ¹H NMR spectra were recorded on a Bruker (AM 250 or 778 300 MHz) instrument with samples dissolved in CDCl₃. Chemical 779 shifts (δ) are given in parts per million (ppm) with the signal of the 780 residual CHCl₃ of the solvent as reference (7.24 ppm for ¹H NMR). 781 The following abbreviations were used to describe the multiplicities: s 782 (singlet), d (doublet), t (triplet), q (quadruplet), quint (quintet), m 783 (multiplet), brs (broad singlet). All multiplicities were approximated 784 to the first order; coupling constants, *J*, are reported in hertz and with 785 an accuracy of 0.5 unit of the last digit. 786

4.4.2. Fourier Transform Infrared Spectroscopy in Attenuated 787 Total Reflection (ATR-FTIR). The ATR-FTIR spectra are recorded on 788 a Bruker Equinox FTIR spectrometer, coupled to a nitrogen-purged 789 external ATR compartment, including a liquid-nitrogen-cooled MCT 790 detector. All spectra are recorded in s- and p-polarization in the 791 spectral range of 900-4000 cm⁻¹ (150 scans, 4 cm⁻¹ resolution). The 792 spectra are presented in absorbance (computed using natural 793 logarithm) and are normalized to the reflection number (around 794 26). The reference spectra are that of the hydrogenated SiHx surfaces. 795 The calibration was performed in a homemade PTFCE IR cell of ~2 796 mL volume. On the top and the bottom of the cell, a PTFE tube (0.8 797 mm diameter) is connected allowing for the addition of different 798 solutions without breaking the spectrometer purge. On the side, there 799 is a 9 mm diameter opening against which the Si prism (sample) is 800 pressed via a nitrile O-ring seal. 801

802 4.4.3. X-ray Photoelectron Spectroscopy (XPS). These measure-803 ments were performed on a K-Alpha spectrometer from Thermo 804 Fisher, equipped with a monochromatic X-ray Source (Al K α , 1486.6 805 eV). For all measurements, a spot size of 400 mm was employed. The 806 hemispherical analyzer was operated in CAE (Constant Analyzer 807 Energy) mode, with a pass energy of 200 eV and a step of 1 eV for the 808 acquisition of surveys spectra, and a pass energy of 50 eV and a step of 809 0.1 eV for the acquisition of high-resolution spectra. A "dual-beam" 810 flood gun was used to neutralize the charge buildup. The recorded 811 spectra were processed by means of Avantage software provided by 812 Thermo Fisher using a peak fitting routine with Shirley background 813 and symmetrical Gaussian-Lorentzian lineshapes. The quantification 814 was performed after normalization of the peak areas with Scofield 815 sensitivity factors. The calibration in binding energy was made by considering that the Csp3 component of C 1s lies at 285 eV. 816

817 4.4.4. Contact Angle. Static contact angle measurement was 818 performed using a DSA100 Kruss analyzer. The water contact angle 819 was measured by depositing a 3 μ L droplet of UPW on the surface, 820 the average contact angle was calculated from three droplets for each 821 surface, and errors were calculated as standard deviation.

4.4.5. Atomic Force Microscopy. Images were recorded under N_2 atmosphere using AFM operating in AC-mode (PicoSPM 5500, Agilent) and silicon tips (HQ-NSC16S cantilevers from Mikro-Mikro-Mikro-No measure the thickness of the organic layers, part of the layer was locally removed by scratching using a syringe needle. The are thickness was deduced from cross sections and histograms of the height distribution on images captured at the frontier between the bare silicon (inside the scratch) and the top of the organic layer.

4.4.6. Ellipsometry. Thickness measurements were carried out an Accurion nanofilm EP3 ellipsometer. The thickness is obtained by measuring the change in the polarization of light (at fixed $\lambda = 658$ nm) as it is reflected off the surface over a range of angles (from 50 to 75° with 1 step number). Thicknesses are obtained with an accuracy of up to a fraction of nanometer.

836 ASSOCIATED CONTENT

837 **Supporting Information**

838 The Supporting Information is available free of charge at 839 https://pubs.acs.org/doi/10.1021/acsapm.2c01632.

- 840 IR quantification of the chemical groups on crystalline Si
- 841 (SI-I); surface characterization of grafted initiators (SI-
- 842 II); and calibration of the polystyrene IR absorption (SI-843 III) (PDF)

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Notes

The authors declare no competing financial interest. 896 The authors declare that they have no known competing 897 financial interests or personal relationships that could have 898 appeared to influence the work reported in this paper. 899

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REFERENCES

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895

(1) Rasouli, R.; Barhoum, A.; Uludag, H. A Review of Nano- 905 structured Surfaces and Materials for Dental Implants: Surface 906 Coating, Patterning and Functionalization for Improved Performance. 907 *Biomater. Sci.* **2018**, *6*, 1312–1338. 908

(2) Kumari, S.; Tiyyagura, H. R.; Pottathara, Y. B.; Sadasivuni, K. K.; 909 Ponnamma, D.; Douglas, T. E. L.; Skirtach, A. G.; Mohan, M. K. 910 Surface Functionalization of Chitosan as a Coating Material for 911 Orthopaedic Applications: A Comprehensive Review. *Carbohydr.* 912 *Polym.* **2021**, 255, No. 117487. 913

(3) Wieszczycka, K.; Staszak, K.; Wozniak-Budych, M. J.; 914 Litowczenko, J.; Maciejewska, B. M.; Jurga, S. Surface Functionaliza- 915 tion—The Way for Advanced Applications of Smart Materials. *Coord.* 916 *Chem. Rev.* **2021**, 436, No. 213846. 917

(4) Liu, J.; Yao, Y.; Li, X. H.; Zhang, Z. J. Fabrication of Advanced 918 Polydimethylsiloxane-based Functional Materials: Bulk Modifications 919 and Surface Functionalizations. *Chem. Eng. J.* **2021**, 408, No. 127612. 920 (5) Long, W.; Ouyang, H.; Hu, X.; Liu, M. Y.; Zhang, X. Y.; Feng, Y. 921 L.; Wei, Y. State-of-Art Review on Preparation, Surface Functionaliza- 922

J

923 tion and Biomedical Applications of Cellulose Nanocrystals-based 924 Materials. *Int. J. Biol. Macromol.* **2021**, *186*, 591–615.

925 (6) Azzaroni, O. Polymer Brushes Here, There, and Everywhere: 926 Recent Advances in their Practical Applications and Emerging 927 Opportunities in Multiple Research Fields. *J. Polym. Sci., Part A:* 928 *Polym. Chem.* **2012**, *50*, 3225–3258.

929 (7) Zoppe, J. O.; Ataman, N. C.; Mocny, P.; Wang, J.; Moraes, J.; 930 Klok, H. A. Surface-Initiated Controlled Radical Polymerization: 931 State-of-the-Art, Opportunities, and Challenges in Surface and 932 Interface Engineering with Polymer Brushes. *Chem. Rev.* **2017**, *117*, 933 1105–1318.

934 (8) Ma, S. H.; Zhang, X. Q.; Yu, B.; Zhou, F. Brushing Up 935 Functional Materials. *NPG Asia Mater.* **2019**, *11*, 24.

936 (9) Nasef, M. M.; Gupta, B.; Shameli, K.; Verma, C.; Ali, R. R.; Ting,

937 T. M. Engineered Bioactive Polymeric Surfaces by Radiation Induced 938 Graft Copolymerization: Strategies and Applications. *Polymers* **2021**, 939 *13*, 3102.

940 (10) Bedel, S.; Lepoittevin, B.; Costa, L.; Leroy, O.; Dragoe, D.;
941 Bruzaud, J.; Herry, J. M.; Guilbaud, M.; Bellon-Fontaine, M. N.;
942 Roger, P. Antibacterial Poly(thylene terephthalate) Surfaces Obtained
943 from Thymyl Methacrylate Polymerization. J. Polym. Sci., Part A:

944 Polym. Chem. 2015, 53, 1975–1985. 945 (11) Anjum, S.; Singh, S.; Lepoittevin, B.; Roger, P.; Panigrahi, M.;

946 Gupta, B. Biomodification Strategies for the Development of 947 Antimicrobial Urinary Catheters: Overview and Advances. *Global* 948 *Challenges* **201**7, *2*, No. 1700068.

949 (12) Edwards, J. V.; Vigo, T. L. *Bioactive Fibers and Polymers*, ACS 950 Symposium Series; Springer, 2001; p 792.

951 (13) Lejars, M.; Margaillan, A.; Bressy, C. Fouling Release Coatings:
952 A Nontoxic Alternative to Biocidal Antifouling Coatings. *Chem. Rev.*953 2012, 112, 4347–4390.

954 (14) Gautam, B.; Yu, H. H. Self-Cleaning Cotton Obtained after 955 Grafting Thermoresponsive Poly(N-vinylcaprolactam) through Sur-956 face-Initiated Atom Transfer Radical Polymerization. *Polymers* **2020**, 957 *12*, 2920.

958 (15) Zhu, Z. Y.; Huang, Z. N.; Huang, W.; Wen, H.; Zhang, J. Y.;
959 Wang, P.; Peng, Y.; Liu, C. K. Polymer Brush-Grafted Cotton Fiber
960 for the Efficient Removal of Aromatic Halogenated Disinfection By961 products in Drinking Water. *J. Colloid Interface Sci.* 2021, 597, 66–74.
962 (16) Hyder, M. K. M. Z.; Ochiai, B. Synthesis of a Highly Selective
963 Scavenger of Precious Metals from a Printed Circuit Board Based on
964 Cellulose Filter Paper Functionalized with a Grafted Polymer Chain

965 Bearing N-Methyl-2-hydroxyethylcarbamothioate Moieties. *ACS* 966 Omega **2022**, 7, 10355–10364.

967 (17) Wei, Q. B.; Cai, M. R.; Zhou, F.; Liu, W. M. Dramatically 968 Tuning Friction Using Responsive Polyelectrolyte Brushes. *Macro-*969 molecules **2013**, 46, 9368–9379.

970 (18) Wang, S. G.; Wang, Z. W.; Li, J.; Li, L. Q.; Hu, W. P. Surface-971 grafting Polymers: from Chemistry to Organic Electronics. *Mater.* 972 *Chem. Front.* **2020**, *4*, 692–714.

973 (19) Gill, C. S.; Long, W.; Jones, C. W. Magnetic Nanoparticle 974 Polymer Brush Catalysts: Alternative Hybrid Organic/Inorganic 975 Structures to Obtain High, Local Catalyst Loadings for Use in 976 Organic Transformations. *Catal. Lett.* **2009**, *131*, 425–431.

977 (20) Zhao, B.; Brittain, W. J. Polymer Brushes: Surface-Immobilized 978 Macromolecules. *Progr. Polym. Sci.* **2000**, *25*, 677–710.

979 (21) Tsujii, Y.; Ohno, K.; Yamamoto, S.; Goto, A.; Fukuda, T. 980 Structure and Properties of High-Density Polymer Brushes Prepared 981 by Surface-Initiated Living Radical Polymerization. In *Surface-Initiated* 982 *Polymerization I. Advances in Polymer Science*, Jordan, R., Ed.; Springer: 983 Berlin, Heidelberg, 2006; Vol. 197, pp 1–45.

984 (22) Yamamoto, S.; Ejaz, M.; Tsujii, Y.; Matsumoto, M.; Fukuda, T. 985 Surface Interaction Forces of Well-Defined, High-Density Polymer 986 Brushes Studied by Atomic Force Microscopy. 1. Effect of Chain 987 Length. *Macromolecules* **2000**, *33*, 5602–5607.

988 (23) Yamamoto, S.; Ejaz, M.; Tsujii, Y.; Fukuda, T. Surface 989 Interaction Forces of Well-Defined, High-Density Polymer Brushes 990 Studied by Atomic Force Microscopy. 2. Effect of Graft Density. 991 *Macromolecules* **2000**, *33*, 5608–5612. (24) Flejszar, M.; Chmielarz, P. Surface-Initiated Atom Transfer 992 Radical Polymerization for the Preparation of Well-Defined Organic- 993 Inorganic Hybrid Nanomaterials. *Materials* **2019**, *12*, 3030. 994

(25) Pyun, J.; Kowalewski, T.; Matyjaszewski, K. Synthesis of 995 Polymer Brushes Using Atom Transfer Radical Polymerization. 996 *Macromol. Rapid Commun.* **2003**, *24*, 1043–1059. 997

(26) Gao, H. F.; Matyjaszewski, K. Synthesis of Star Polymers by a 998 Combination of ATRP and the "Click" Coupling Method. *Macro-* 999 *molecules* **2006**, *39*, 4960–4965.

(27) Matyjaszewski, K.; Miller, P. J.; Shukla, N.; Immaraporn, B.; 1001 Gelman, A.; Luokala, B. B.; Siclovan, T. M.; Kickelbick, G.; Vallant, 1002 T.; Hoffmann, H.; Pakula, T. Polymers at Interfaces: Using Atom 1003 Transfer Radical Polymerization in the Controlled Growth of 1004 Homopolymers and Block Copolymers from Silicon surfaces in the 1005 Absence of Untethered Sacrificial Initiator. *Macromolecules* **1999**, *32*, 1006 8716–8724. 1007

(28) Ejaz, M.; Yamamoto, S.; Ohno, K.; Tsujii, Y.; Fukuda, T. 1008 Controlled Graft Polymerization of Methyl Methacrylate on Silicon 1009 Substrate by the Combined Use of the Langmuir-Blodgett and Atom 1010 Transfer Radical Polymerization Techniques. *Macromolecules* **1998**, 1011 *31*, 5934–5936. 1012

(29) Zaborniak, I.; Chmielarz, P.; Wolski, K. Riboflavin-Induced 1013 Metal-Free ATRP of (Meth)acrylates. *Eur. Polym. J.* **2020**, *140*, 1014 No. 110055. 1015

(30) Zaborniak, I.; Chmielarz, P.; Matyjaszewski, K. Synthesis of 1016 Riboflavin-Based Macromolecules through Low ppm ATRP in 1017 Aqueous Media. *Macromol. Chem. Phys.* **2020**, 221, No. 1900496. 1018

(31) Pan, X.; Fantin, M.; Yuan, F.; Matyjaszewski, K. Externally 1019 Controlled Atom Transfer Radical Polymerization. *Chem. Soc. Rev.* 1020 **2018**, 47, 5457–5490. 1021

(32) Li, D.; Niu, X. Q.; Yang, S. Y.; Chen, Y. H.; Ran, F. Thermo- 1022 Responsive Polysulfone Membranes with Good Anti-Fouling Property 1023 Modified by Grafting Random Copolymers via Surface-Initiated 1024 eATRP. *Sep. Purif. Technol.* **2018**, 206, 166–176. 1025

(33) Strover, L. T.; Malmstrom, J.; Stubbing, L. A.; Brimble, M. A.; 1026 Travas-Sejdic, J. Electrochemically-Controlled Grafting of Hydro- 1027 philic Brushes from Conducting Polymer Substrates. *Electrochim. Acta* 1028 **2016**, 188, 57–70. 1029

(34) Chmielarz, P.; Krys, P.; Park, S.; Matyjaszewski, K. PEO-b- 1030 PNIPAM Copolymers via SARA ATRP and eATRP in Aqueous 1031 Media. *Polymer* **2015**, *71*, 143–147. 1032

(35) Dadashi-Silab, S.; Doran, S.; Yagci, Y. Photoinduced Electron 1033 Transfer Reactions for Macromolecular Syntheses. *Chem. Rev.* 2016, 1034 *116*, 10212–10275. 1035

(36) Razeghi, R.; Kazemi, F.; Nikfarjam, N.; Shariati, Y.; Kaboudin, 1036 B. Visible Photo-Induced Catalyst-Free Polymerization via In Situ 1037 Prepared Dibromide. *Eur. Polym. J.* **2021**, *144*, No. 110195. 1038

(37) Fors, B. P.; Hawker, C. J. Control of a Living Radical 1039 Polymerization of Methacrylates by Light. *Angew. Chem., Int. Ed.* 1040 **2012**, *51*, 8850–8853. 1041

(38) Jordan, R.; Ulman, A.; Kang, J. F.; Rafailovich, M. H.; Sokolov, 1042 J. Surface-Initiated Anionic Polymerization of Styrene by Means of 1043 Self-Assembled Monolayers. J. Am. Chem. Soc. **1999**, 121, 1016–1022. 1044

(39) Wang, S. Q.; Zhu, Y. X. Facile Method to Prepare Smooth and 1045 Homogeneous Polymer Brush Surfaces of Varied Brush Thickness 1046 and Grafting Density. *Langmuir* **2009**, *25*, 13448–13455. 1047

(40) Słowikowska, M.; Chajec, K.; Michalski, A.; Zapotoczny, S.; 1048
Wolski, K. Surface-Initiated Photoinduced Iron-Catalyzed Atom 1049
Transfer Radical Polymerization with ppm Concentration of FeBr3 1050
under Visible Light. *Materials* 2020, 13, 5139.

(41) Bech, L.; Elzein, T.; Meylheuc, T.; Ponche, A.; Brogly, M.; 1052 Lepoittevin, B.; Roger, P. Atom Transfer Radical Polymerization of 1053 Styrene from Different Poly(ethylene terephthalate) Surfaces: Films, 1054 Fibers and Fabrics. *Eur. Polym. J.* **2009**, *45*, 246–255. 1055

(42) Boukherroub, R.; Morin, S.; Bensebaa, F.; Wayner, D. D. M. 1056 New Synthetic Routes to Alkyl Monolayers on the Si(111) Surface. 1057 *Langmuir* **1999**, *15*, 3831–3835. 1058

(43) Jakob, P.; Chabal, Y. J. Chemcial Etching of Vicinal Si(111)— 1059 Dependence of the Surface-Structure and the Hydrogen Termination 1060 1061 on the pH of the Etching Solutions. J. Chem. Phys. **1991**, 95, 2897–1062 2909.

1063 (44) Karimi, M.; Tashvigh, A. A.; Asadi, F.; Ashtiani, F. Z. 1064 Determination of Concentration-Dependent Diffusion Coefficient of 1065 Seven Solvents in Polystyrene Systems using FTIR-ATR Technique: 1066 Experimental and Mathematical Studies. *RSC Adv.* **2016**, *6*, 9013– 1067 9022.

1068 (45) Ozanam, F.; Chazalviel, J. N. Fourier-Transform Electrochemi-1069 cally Modulated Infrared-Spectroscopy. J. Electron Spectrosc. Relat. 1070 Phenom. **1987**, 45, 323–334.

1071 (46) Bélanger, D.; Pinson, J. Electrografting: A Powerful Method for 1072 Surface Modification. *Chem. Soc. Rev.* **2011**, *40*, 3995–4048.

1073 (47) Fabre, B. Functionalization of Oxide-Free Silicon Surfaces with 1074 Redox-Active Assemblies. *Chem. Rev.* **2016**, *116*, 4808–4849.

1075 (48) Gooding, J. J.; Ciampi, S. The Molecular Level Modification of 1076 Surfaces: From Self-Assembled Monolayers to Complex Molecular 1077 Assemblies. *Chem. Soc. Rev.* **2011**, *40*, 2704–2718.

1078 (49) Chabal, Y. J. Surface Infrared-Spectroscopy. *Surf. Sci. Rep.* **1988**, 1079 *8*, 211–357.

1080 (50) Faucheux, A.; Gouget-Laemmel, A. C.; Henry de Villeneuve, 1081 C.; Boukherroub, R.; Ozanam, F.; Allongue, P.; Chazalviel, J.-N. Well-1082 Defined Carboxyl-Terminated Alkyl Monolayers Grafted onto H-1083 Si(111): Packing Density from a Combined AFM and Quantitative IR 1084 Study. *Langmuir* **2006**, *22*, 153–162.

1085 (51) Aschl, T.; Frison, G.; Moraillon, A.; Ozanam, F.; Allongue, P.; 1086 Gouget-Laemmel, A. C. Insights into the Ochratoxin A/Aptamer 1087 Interactions on a Functionalized Silicon Surface by Fourier Transform 1088 Infrared and UV-Vis Studies. *Langmuir* **2020**, *36*, 13908–13917.

1089 (52) Francis, R.; Lepoittevin, B.; Taton, D.; Gnanou, Y. Toward an 1090 Easy Access to Asymmetric Stars and Miktoarm Stars by Atom 1091 Transfer Radical Polymerization. *Macromolecules* **2002**, *35*, 9001– 1092 9008.

1093 (53) Xia, J. H.; Matyjaszewski, K. Controlled/"Living" Radical 1094 Polymerization. Atom Transfer Radical Polymerization Using Multi-1095 dentate Amine Ligands. *Macromolecules* **1997**, *30*, 7697–7700.

1096 (54) Zidelmal, N.; Aubry-Barroca, N.; Lepoittevin, B.; Mellah, M.; 1097 Costa, L.; Ozanam, F.; Gouget-Laemmel, A. C.; Schulz, E.; Roger, P. 1098 Synthesis, Characterization and Catalytic Properties of Salen-1099 Containing Polymers Obtained by Atom Transfer Radical Polymer-1100 ization. *Polymer* **2018**, *135*, 261–270.

1101 (55) Sam, S.; Touahir, L.; Salvador Andresa, J.; Allongue, P.; 1102 Chazalviel, J.-N.; Gouget-Laemmel, A. C.; Henry de Villeneuve, C.; 1103 Moraillon, A.; Ozanam, F.; Gabouze, N.; Djebbar, S. Semiquantitative 1104 Study of the EDC/NHS Activation of Acid Terminal Groups at 1105 Modified Porous Silicon Surfaces. *Langmuir* **2010**, *26*, 809–814.

1106 (56) Palazon, F.; Benavides, C. M.; Leonard, D.; Souteyrand, E.; 1107 Chevolot, Y.; Cloarec, J. P. Carbodiimide/NHS Derivatization of 1108 COOH-Terminated SAMs: Activation or Byproduct Formation? 1109 Langmuir **2014**, 30, 4545–4550.

1110 (57) Zhang, C.; Luo, N.; Hirt, D. E. Surface Grafting Polyethylene 1111 glycol (PEG) onto Poly(ethylene-co-acrylic acid) films. *Langmuir* 1112 **2006**, *22*, 6851–6857.

1113 (58) Oliverio, M.; Perotto, S.; Messina, G. C.; Lovato, L.; De 1114 Angelis, F. Chemical Functionalization of Plasmonic Surface 1115 Biosensors: A Tutorial Review on Issues, Strategies, and Costs. ACS 1116 Appl. Mater. Interfaces **2017**, *9*, 29394–29411.

(59) Lepoittevin, B.; Costa, L.; Pardoue, S.; Dragoe, D.; Mazerat, S.;
Roger, P. Hydrophilic PET Surfaces by Aminolysis and Glycopolymer
Brushes Chemistry. J. Polym. Sci., Part A: Polym. Chem. 2016, 54,
2689–2697.

1121 (60) Xu, Y.; Sui, X.; Guan, S.; Zhai, J.; Gao, L. Olfactory Sensory 1122 Neuron-Mimetic CO2 Activated Nanofluidic Diode with Fast 1123 Response Rate. *Adv. Mater.* **2015**, *27*, 1851–1855.

(61) Moraillon, A.; Gouget-Laemmel, A. C.; Ozanam, F.; Chazalviel,
J.-N. Amidation of Monolayers on Silicon in Physiological Buffers: A
Quantitative IR Study. J. Phys. Chem. C 2008, 112, 7158–7167.

1127 (62) Sieval, A. B.; van den Hout, B.; Zuilhof, H.; Sudhölter, E. J. R. 1128 Molecular Modeling of Alkyl Monolayers on the Si(111) Surface. 1129 Langmuir **2000**, *16*, 2987–2990. (63) Wang, Z.; Zuilhof, H. Self-Healing Fluoropolymer Brushes as 1130 Highly Polymer-Repellent Coatings. J. Mater. Chem. A **2016**, *4*, 2408–1131 2412.

(64) Yu, W. H.; Kang, E. T.; Neoh, K. G.; Zhu, S. P. Controlled 1133 Grafting of Well-Defined Polymers on Hydrogen-Terminated Silicon 1134 Substrates by Surface-Initiated Atom Transfer Radical olymerization. 1135 *J. Phys. Chem. B* **2003**, *107*, 10198–10205. 1136

(65) Yang, Q.; Tian, J.; Hu, M.-X.; Xu, Z.-K. Construction of a 1137 Comb-Like Glycosylated Membrane Surface by a Combination of 1138 UV-Induced Graft Polymerization and Surface-Initiated ATRP. 1139 *Langmuir* **2007**, 23, 6684–6690. 1140

(66) Bozukova, D.; Pagnoulle, C.; De Pauw-Gillet, M.-C.; Ruth, N.; 1141 Jerome, R.; Jerome, C. Imparting Antifouling Properties of Poly(2- 1142 hydroxyethyl methacrylate) Hydrogels by Grafting Poly(oligoethylene 1143 glycol methyl ether acrylate). *Langmuir* **2008**, *24*, 6649–6658. 1144

(67) daFonseca, C.; Ozanam, F.; Chazalviel, J. N. In Situ Infrared 1145 Characterisation of the Interfacial Oxide During the Anodic 1146 Dissolution of a Silicon Electrode in Fluoride Electrolytes. *Surf. Sci.* 1147 **1996**, 365, 1–14. 1148

(68) Wallart, X.; de Villeneuve, C. H.; Allongue, P. Truly 1149 Quantitative XPS Characterization of Organic Monolayers on Silicon: 1150 Study of Alkyl and Alkoxy Monolayers on H-Si(111). *J. Am. Chem.* 1151 *Soc.* **2005**, *127*, 7871–7878. 1152

(69) Al-Bataineh, S. A.; Britcher, L. G.; Griesser, H. J. Rapid 1153 Radiation Degradation in the XPS Analysis of Antibacterial Coatings 1154 of Brominated Furanones. *Surf. Interface Anal.* **2006**, *38*, 1512–1518. 1155

(70) Bedel, S.; Lepoittevin, B.; Costa, L.; Leroy, O.; Dragoe, D.; 1156 Bruzaud, J.; Herry, J.-M.; Guilbaud, M.; Bellon-Fontaine, M.-N.; 1157 Roger, P. Antibacterial Poly(ethylene terephthalate) Surfaces 1158 Obtained from Thymyl Methacrylate Polymerization. J. Polym. Sci., 1159 Part A: Polym. Chem. 2015, 53, 1975–1985. 1160

(71) Liang, C. Y.; Krimm, S. Infrared Spectra of High Polymers. 6. 1161 Polystyrene. J. Polym. Sci. **1958**, 27, 241–254. 1162

(72) Neppel, A.; Butler, I. S. Infrared and Raman-Spectra of 1163 Poly(alpha-methyl styrene). Spectrochim. Acta, Part A **1984**, 40, 1164 1095–1100. 1165

(73) Hinode, K.; Takeda, K.; Kondo, S. Abnormal Room- 1166 Temperature Oxidation of Silicon in the Presence of Copper. J. 1167 Vac. Sci. Technol., A 2002, 20, 1653–1658.

(74) Bakangura, E.; Roger, P.; Soares, R. S. B.; Mellah, M.; Barroca- 1169 Aubry, N.; Gouget-Laemmel, A. C.; Ozanam, F.; Costa, L.; Baltaze, J. 1170 P.; Schulz, E. Post-Modification of Copolymers Obtained by ATRP 1171 for an Application in Heterogeneous Asymmetric Salen Catalysis. 1172 *Molecules* **2022**, *27*, 4654. 1173